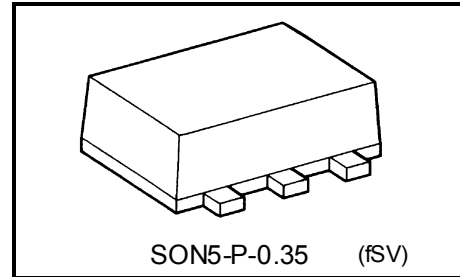


TC7SH07FS

NON-Inverter (Open Drain)

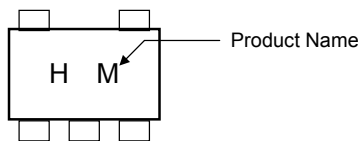
Features

- High speed: $t_{pZL} = 3.7 \text{ ns (typ.)}$ at $V_{CC} = 5 \text{ V}$, 15 pF
- Low power dissipation: $I_{CC} = 2 \text{ }\mu\text{A (max)}$ at $T_a = 25^\circ\text{C}$
- Wide operating voltage range: $V_{CC} \text{ (opr.)} = 2 \text{ to } 5.5 \text{ V}$
- 5.5-V tolerant input
- 5.5-V power down protection output

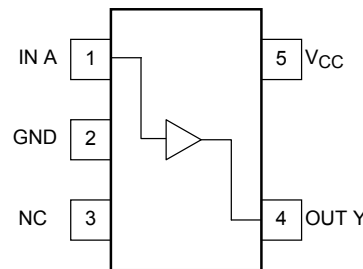


Weight : 0.001 g (Typ.)

Marking



Pin Assignment (top view)



Absolute Maximum Ratings ($T_a = 25^\circ\text{C}$)

| Characteristics | Symbol | Rating | Unit |
|-----------------------------|-----------|---------------------------------|------------------|
| Supply voltage range | V_{CC} | -0.5 to 7 | V |
| DC input voltage | V_{IN} | -0.5 to 7 | V |
| DC output voltage | V_{OUT} | -0.5 to 7 (Note 1) | V |
| | | -0.5 to $V_{CC} + 0.5$ (Note 2) | |
| Input diode current | I_{IK} | -20 | mA |
| Output diode current | I_{OK} | -20 (Note 3) | mA |
| DC output current | I_{OUT} | 25 | mA |
| DC V_{CC} /ground current | I_{CC} | ± 50 | mA |
| Power dissipation | P_D | 50 | mW |
| Storage temperature | T_{stg} | -65 to 150 | $^\circ\text{C}$ |

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

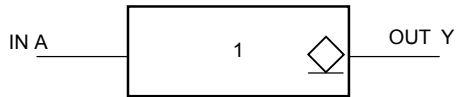
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: $V_{CC} = 0\text{V}$ or high impedance condition

Note 2: Low state. Do not exceed I_{OUT} of absolute maximum ratings.

Note 3: $V_{OUT} < \text{GND}$

IEC Logic Symbol



Truth Table

| A | Y |
|---|---|
| L | L |
| H | Z |

Z: High impedance

Operating Ranges

| Characteristics | Symbol | Rating | Unit |
|--------------------------|-----------|--------------------------------------|------|
| Supply voltage | V_{CC} | 2 to 5.5 | V |
| Input voltage | V_{IN} | 0 to 5.5 | V |
| Output voltage | V_{OUT} | 0 to V_{CC} | V |
| Operating temperature | T_{opr} | -40 to 85 | °C |
| Input rise and fall time | dt/dv | 0 to 100 ($V_{CC} = 3.3 \pm 0.3$ V) | ns/V |
| | | 0 to 20 ($V_{CC} = 5.0 \pm 0.5$ V) | |

Electrical Characteristics

DC Characteristics

| Characteristics | Symbol | Test Condition | | Ta = 25°C | | | Ta = -40 to 85°C | | Unit | |
|--------------------------------|------------------|---|-------------------------|---------------------|-----------------------|------|-----------------------|-----|-----------------------|-----|
| | | | | V _{CC} (V) | Min | Typ. | Max | Min | | Max |
| High-level input voltage | V _{IH} | — | | 2.0 | 1.5 | — | — | 1.5 | — | V |
| | | | | 3.0 to 5.5 | V _{CC} × 0.7 | — | — | — | V _{CC} × 0.7 | |
| Low-level input voltage | V _{IL} | — | | 2.0 | — | — | 0.5 | — | 0.5 | V |
| | | | | 3.0 to 5.5 | — | — | V _{CC} × 0.3 | — | V _{CC} × 0.3 | |
| Low-level output voltage | V _{OL} | V _{IN} = V _{IL} | I _{OL} = 50 μA | 2.0 | — | 0 | 0.1 | — | 0.1 | V |
| | | | | 3.0 | — | 0 | 0.1 | — | 0.1 | |
| | | | | 4.5 | — | 0 | 0.1 | — | 0.1 | |
| | | | I _{OL} = 4 mA | 3.0 | — | — | 0.36 | — | 0.44 | |
| | | | | 4.5 | — | — | 0.36 | — | 0.44 | |
| Input leakage current | I _{IN} | V _{IN} = 5.5 V or GND | | 0 to 5.5 | — | — | ±0.1 | — | ±1.0 | μA |
| Output Z level leakage current | I _{LKG} | V _{IN} = V _{IH} V _{OUT} = 0 to 5.5V | | 0 to 5.5 | — | — | ±0.25 | — | ±2.5 | μA |
| Power-off leakage current | I _{OFF} | V _{IN} = 5.5V or V _{OUT} = 0 to 5.5V | | 0.0 | — | — | 1.0 | — | 10.0 | μA |
| Quiescent supply current | I _{CC} | V _{IN} = V _{CC} or GND | | 5.5 | — | — | 2.0 | — | 20 | μA |

AC Characteristics (Input: $t_r = t_f = 3$ ns)

| Characteristics | Symbol | Test Condition | Ta = 25°C | | | | Ta = -40 to 85°C | | Unit | |
|-------------------------------|------------------|----------------------|-----------|----|-----|------|------------------|-----|------|-----|
| | | | VCC (V) | | Min | Typ. | Max | Min | | Max |
| Propagation delay time | t _{pZL} | R _L = 1kΩ | 3.3 ± 0.3 | 15 | — | 5.5 | 7.9 | 1.0 | 9.5 | ns |
| | | | | 50 | — | 8.0 | 11.4 | 1.0 | 13.0 | |
| | | | 5.0 ± 0.5 | 15 | — | 3.7 | 5.5 | 1.0 | 6.5 | |
| | | | | 50 | — | 5.2 | 7.5 | 1.0 | 8.5 | |
| | t _{pLZ} | R _L = 1kΩ | 3.3 ± 0.3 | 15 | — | 5.5 | 7.9 | 1.0 | 9.5 | |
| | | | | 50 | — | 8.0 | 11.4 | 1.0 | 13.0 | |
| | | | 5.0 ± 0.5 | 15 | — | 3.7 | 5.5 | 1.0 | 6.5 | |
| | | | | 50 | — | 5.2 | 7.5 | 1.0 | 8.5 | |
| Input capacitance | C _{IN} | — | | — | 4 | 10 | — | 10 | pF | |
| Output capacitance | C _{OUT} | — | | — | 6 | — | — | — | pF | |
| Power dissipation capacitance | C _{PD} | (Note4) | | | — | 14 | — | — | — | pF |

Note 4: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

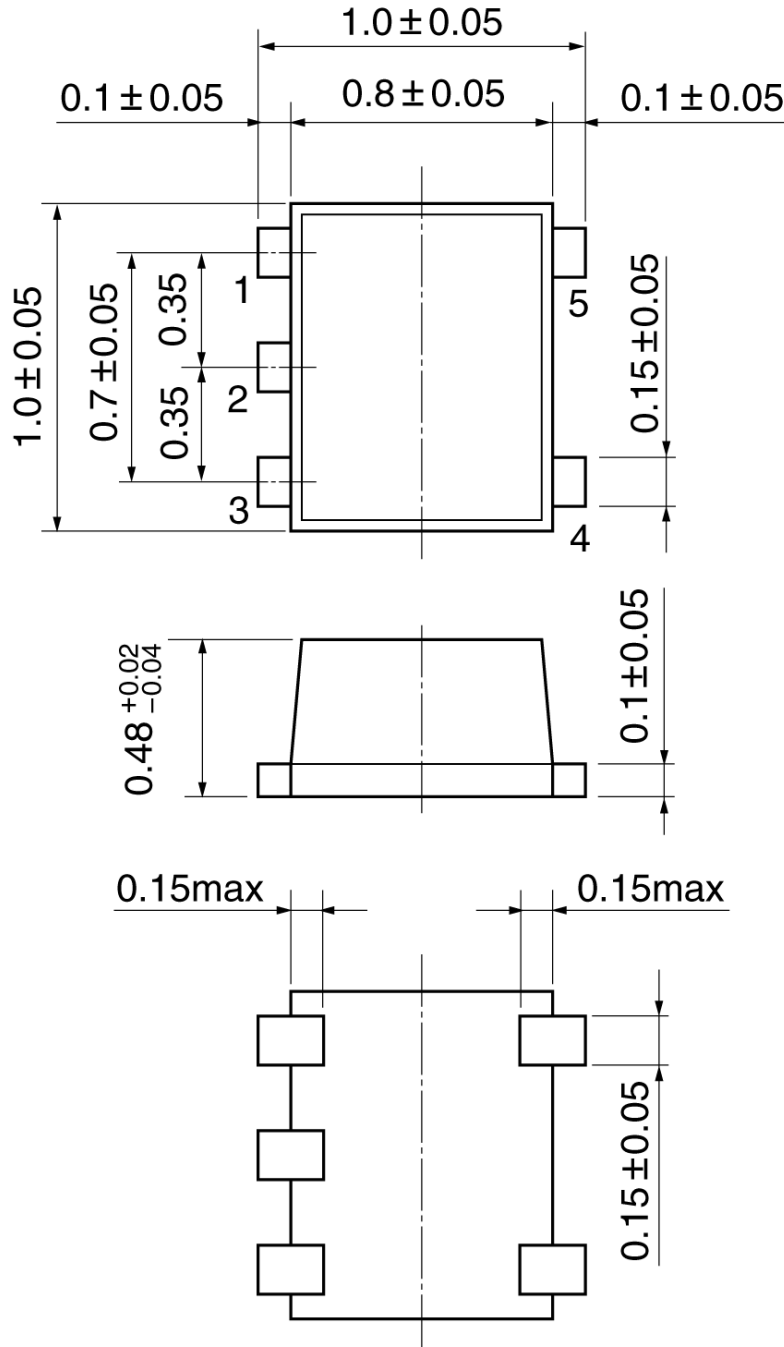
Average operating current can be obtained by the equation:

$$I_{CC (opr.)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$$

Package Dimensions

SON5-P-0.35

Unit: mm



Weight: 0.001 g (typ.)

RESTRICTIONS ON PRODUCT USE

20070701-EN GENERAL

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